



Sample &

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SN54LVC32A, SN74LVC32A

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SNx4LVC32A Quadruple 2-Input Positive-OR Gates

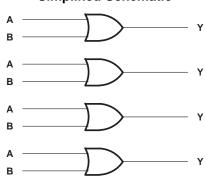
Features 1

- Operate From 1.65 V to 3.6 V
- Specified From -40°C to +85°C, -40°C to +125°C, and -55°C to +125°C
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 3.8 ns at 3.3 V
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot) > 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model
 - 200-V Machine Model
 - 1000-V Charged-Device Model

Applications 2

- **AV Receivers**
- Audio Docks: Portable
- Blu-ray Players and Home Theater
- MP3 Players or Recorders
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drives (SSDs): Client and Enterprise
- TVs: LCD, Digital, and High-Definition (HDTV)
- **Tablets: Enterprise**
- Video Analytics: Server
- Wireless Headsets, Keyboards, and Mice

Simplified Schematic



3 Description

The SN54LVC32A quadruple 2-input positive-OR gate is designed for 2.7-V to 3.6-V V_{CC} operation, and the SN74LVC32A quadruple 2-input positive-OR gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The SNx4LVC32A devices perform the Boolean function Y = A + B or $Y = \overline{A} \cdot \overline{B}$ in positive logic.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

Device Information ⁽¹⁾									
PART NUMBER	PACKAGE	BODY SIZE (NOM)							
SN74LVC32AD	SOIC (14)	8.65 mm × 3.91 mm							
SN74LVC32ADB	SSOP (14)	6.20 mm × 5.30 mm							
SN74LVC32ANS	SO (14)	10.30 mm × 5.30 mm							
SN74LVC32APW	TSSOP (14)	5.00 mm × 4.40 mm							
SN74LVC32ARGY	VQFN (14)	3.50 mm × 3.50 mm							
SN54LVC32AJ	CDIP (14)	19.56 mm × 6.67 mm							
SN54LVC32AW	CFP (14)	9.21 mm × 5.97 mm							
SN54LVC32AFK	LCCC (20)	8.89 mm × 8.89 mm							

(1) For all available packages, see the orderable addendum at the end of the data sheet.

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.





Page

Page

Table of Contents

1	Feat	ures 1
2	App	lications1
3	Desc	cription1
4	Revi	sion History 2
5	Pin (Configuration and Functions 3
6		cifications
	6.1	Absolute Maximum Ratings 4
	6.2	ESD Ratings 4
	6.3	Recommended Operating Conditions, SN54LVC32A
	6.4	Recommended Operating Conditions, SN74LVC32A
	6.5	Thermal Information
	6.6	Electrical Characteristics, SN54LVC32A 6
	6.7	Electrical Characteristics, SN74LVC32A 6
	6.8	Switching Characteristics, SN54LVC32A7
	6.9	Switching Characteristics, SN74LVC32A7
	6.10	Operating Characteristics7
	6.11	Typical Characteristics 7
7	Para	meter Measurement Information
8	Deta	iled Description9

	8.1	Overview
	8.2	Functional Block Diagram 9
	8.3	Feature Description
	8.4	Device Functional Modes
9	Appl	ication and Implementation 10
	9.1	Application Information 10
	9.2	Typical Application 10
10	Pow	er Supply Recommendations 11
11		out 11
	11.1	Layout Guidelines 11
	11.2	Layout Example 11
12	Devi	ice and Documentation Support 12
	12.1	Related Links 12
	12.2	Receiving Notification of Documentation Updates 12
	12.3	Community Resources 12
	12.4	Trademarks 12
	12.5	Electrostatic Discharge Caution 12
	12.6	Glossary 12
13	Мес	hanical, Packaging, and Orderable
	Infor	mation 12

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

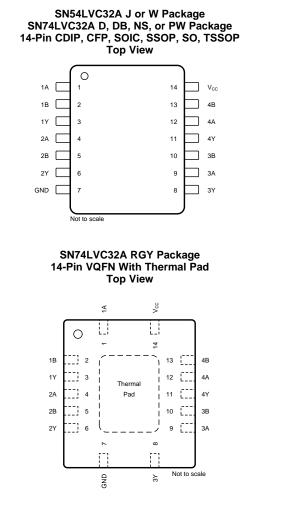
Changes from Revision Q (December 2014) to Revision R

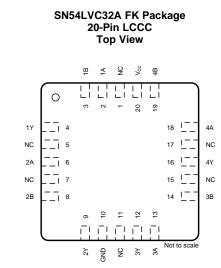
Changes from Revision P (April 2005) to Revision Q

•	Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and	
	Mechanical, Packaging, and Orderable Information section.	
•	Deleted Ordering Information table.	. 1
•	Added Military Disclaimer to Features	. 1



5 Pin Configuration and Functions





NC - No internal connection

Pin Functions

		PIN					
	SN74LV	C32A	SN	54LVC32A	TYPE	DESCRIPTION	
NAME	D, DB, NS, PW	RGY	J, W	FK			
1A	1	1	1	2	I	Gate 1 input	
1B	2	2	2	3	I	Gate 1 input	
1Y	3	3	3	4	0	Gate 1 output	
2A	4	4	4	6	-	Gate 2 input	
2B	5	5	5	8	Ι	Gate 2 input	
2Y	6	6	6	9	0	Gate 2 output	
GND	7	7	7	10	_	Ground Pin	
3Y	8	8	8	12	0	Gate 3 output	
ЗA	9	9	9	13	I	Gate 3 input	
3B	10	10	10	14	I	Gate 3 input	
4Y	11	11	11	16	0	Gate 4 output	
4A	12	12	12	18	I	Gate 4 input	
4B	13	13	13	19	I	Gate 4 input	
V _{CC}	14	14	14	20	_	Power Pin	
NC	—	—	—	1, 5, 7, 11, 15, 17	_	No Connection	

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Specifications 6

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		-0.5	6.5	V
VI	Input voltage ⁽²⁾	Input voltage ⁽²⁾			V
Vo	Output voltage ⁽²⁾⁽³⁾	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	
I _O	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
P _{tot}	Power dissipation	$T_A = -40^{\circ}C$ to $+125^{\circ}C^{(4)(5)}$		500	mW
TJ	Junction temperature				°C
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed. (2)

The value of V_{CC} is provided in the Recommended Operating Conditions tables. (3)

(4)

For the D package: above 70°C, the value of P_{tot} derates linearly with 8 mW/K. For the DB, DGV, NS, and PW packages: above 60°C, the value of P_{tot} derates linearly with 5.5 mW/K. (5)

6.2 ESD Ratings

			VALUE	UNIT	
V		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾			
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	1000	v	

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. (1)

JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. (2)

4



6.3 Recommended Operating Conditions, SN54LVC32A

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			SN54LVC	C32A		
			-55 to +1	–55 to +125°C		
			MIN	MAX		
V	Supply voltage	Operating	2	3.6	N/	
V _{CC}	Supply voltage	Data retention only	1.5		V	
V _{IH}	High-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		V	
V _{IL}	Low-level input voltage	$V_{CC} = 2.7 V \text{ to } 3.6 V$		0.8	V	
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	V _{CC}	V	
	LP-sh lassed as the standard second at	V _{CC} = 2.7 V		-12		
I _{OH}	High-level output current	$V_{CC} = 3 V$		-24	mA	
	I and be also done to a more of	V _{CC} = 2.7 V		12		
I _{OL}	Low-level output current	V _{CC} = 3 V		24	mA	
$\Delta t / \Delta v$	Input transition rise and fall rate	·		7	ns/V	

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See Implications of Slow or Floating CMOS Inputs, SCBA004.

6.4 Recommended Operating Conditions, SN74LVC32A

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			SN74LVC32A							
			T _A = 25	°C	–40 to +4	35°C	–40 to +125°C		UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX		
v	Currely valte as	Operating	1.65	3.6	1.65	3.6	1.65	3.6	V	
V _{CC}	Supply voltage	Data retention only	1.5		1.5		1.5		v	
		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		0.65 × V _{CC}		$0.65 \times V_{CC}$			
VIH	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	1.7		1.7		1.7		V	
	vollage	V_{CC} = 2.7 V to 3.6 V	2		2		2			
	Low-level input voltage	V_{CC} = 1.65 V to 1.95 V	0.3	5 × V _{CC}	0.	35 × V _{CC}		$0.35 \times V_{CC}$		
V _{IL}		V_{CC} = 2.3 V to 2.7 V		0.7		0.7		0.7	V	
		V_{CC} = 2.7 V to 3.6 V		0.8		0.8		0.8		
VI	Input voltage		0	5.5	0	5.5	0	5.5	V	
Vo	Output voltage		0	V _{CC}	0	V_{CC}	0	V _{CC}	V	
		V _{CC} = 1.65 V		-4		-4		-4		
	High-level output	$V_{CC} = 2.3 V$		-8		-8		-8	mA	
I _{OH}	current	$V_{CC} = 2.7 V$		-12		-12		-12	ША	
		$V_{CC} = 3 V$		-24		-24		-24		
		V _{CC} = 1.65 V		4		4		4		
	Low-level output	$V_{CC} = 2.3 V$		8		8		8		
I _{OL}	current	$V_{CC} = 2.7 V$		12		12		12	mA	
		$V_{CC} = 3 V$		24		24		24		
$\Delta t/\Delta v$	Input transition rise a	and fall rate		7		7		7	ns/V	

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See *Implications of Slow or Floating* CMOS Inputs, SCBA004.

SN54LVC32A, SN74LVC32A

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6.5 Thermal Information

THERMAL METRIC ⁽¹⁾			SNx4LVC32A						
		D	DB	NS	PW	RGY	UNIT		
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS			
R_{\thetaJA}	Junction-to-ambient thermal resistance	86	96	76	113	47	°C/W		

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.6 Electrical Characteristics, SN54LVC32A

over operating free-air temperature range (unless otherwise noted)

			SN54LVC32A -55 to +125°C			
PARAMETER	TE	V _{cc}			UNIT	
				MIN N	IAX	
	I _{OH} = −100 μA		2.7 V to 3.6 V	$V_{CC} - 0.2$		
V _{OH}	1 10 m 4	2.7 V	2.2		V	
VOH	I _{OH} = -12 mA		3 V	2.4		v
	I _{OH} = -24 mA		3 V	2.2		
	I _{OL} = 100 μA		2.7 V to 3.6 V		0.2	
V _{OL}	I _{OL} = 12 mA		2.7 V		0.4	V
	I _{OL} = 24 mA		3 V).55	
I _I	V _I = 5.5 V or GND		3.6 V		±5	μA
I _{CC}	$V_I = V_{CC}$ or GND,	I _O = 0	3.6 V		10	μΑ
ΔI_{CC}	One input at V _{CC} – 0.6 V,	Other inputs at V_{CC} or GND	2.7 V to 3.6 V		500	μA

6.7 Electrical Characteristics, SN74LVC32A

over operating free-air temperature range (unless otherwise noted)

			SN74LVC32A						
PARAMETER	TEST CONDITIONS	V _{cc}	T _A =	25°C		–40 to +85°C	-40 to +12	25°C	UNIT
			MIN	TYP	MAX	MIN MAX	K MIN	MAX	
	I _{OH} = -100 μA	1.65 V to 3.6 V	V _{CC} – 0.2			V _{CC} – 0.2	V _{CC} – 0.3		
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.29			1.2	1.05		
V _{OH}	I _{OH} = -8 mA	2.3 V	1.9			1.7	1.55		V
	1. 10 m 4	2.7 V	2.2			2.2	2.05		
	I _{OH} = -12 mA	3 V	2.4			2.4	2.25		
	I _{OH} = -24 mA	3 V	2.3			2.2	2		
	I _{OL} = 100 μA	1.65 V to 3.6 V			0.1	0	2	0.3	
	$I_{OL} = 4 \text{ mA}$	1.65 V			0.24	0.4	5	0.6	
V _{OL}	I _{OL} = 8 mA	2.3 V			0.3	0.	7	0.85	V
	I _{OL} = 12 mA	2.7 V			0.4	0	1	0.6	
	I _{OL} = 24 mA	3 V			0.55	0.5	5	0.8	
l _l	V _I = 5.5 V or GND	3.6 V			±1	±	5	±20	μA
I _{CC}	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	3.6 V			1	1	כ	40	μA
ΔI _{CC}	One input at $V_{CC} - 0.6 V$, Other inputs at V_{CC} or GND	2.7 V to 3.6 V			500	50	D	5000	μA
Ci	$V_I = V_{CC}$ or GND	3.3 V		5					pF

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6.8 Switching Characteristics, SN54LVC32A

over operating free-air temperature range (unless otherwise noted) (see Figure 2)

				SN54LVC	32A	
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	-55 to +12	UNIT	
	((001101)		MIN	MAX	
	A	V	2.7 V		4.4	
t _{pd} A or B		ř	3.3 V ± 0.3 V	1	3.8	ns

6.9 Switching Characteristics, SN74LVC32A

over operating free-air temperature range (unless otherwise noted) (see Figure 2)

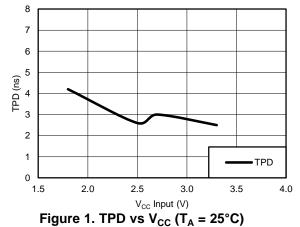
		TO (OUTPUT)		SN74LVC32A							
PARAMETER (INPUT)	FROM (INPUT)		V _{cc}	T _A = 25°C			-40 to	+85°C	–40 to +	·125°C	UNIT
	(001101)		MIN	TYP	MAX	MIN	MAX	MIN	MAX		
		1.8 V ± 0.15 V	1	4.2	8.2	1	8.7	1	10.2		
	A or D	Y	2.5 V ± 0.2 V	1	2.6	4.9	1	5.4	1	6.9	ns
t _{pd}	A or B	ř	2.7 V	1	3	4.2	1	4.4	1	5.5	
		3.3 V ± 0.3 V	1	2.5	3.6	1	3.8	1	5		
t _{sk(o)}			$3.3 \text{ V} \pm 0.3 \text{ V}$					1		1.5	ns

6.10 Operating Characteristics

 $T_A = 25^{\circ}C$

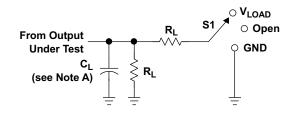
	PARAMETER	TEST CONDITIONS	V _{cc}	ТҮР	UNIT
			1.8 V	7.5	
C _{pd}	Power dissipation capacitance per gate	f = 10 MHz	2.5 V	10.6	pF
			3.3 V	12.5	

6.11 Typical Characteristics



VI

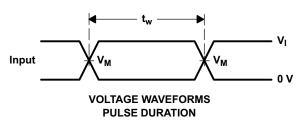
7 Parameter Measurement Information

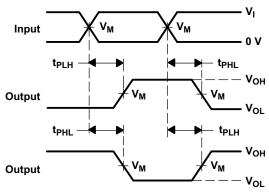


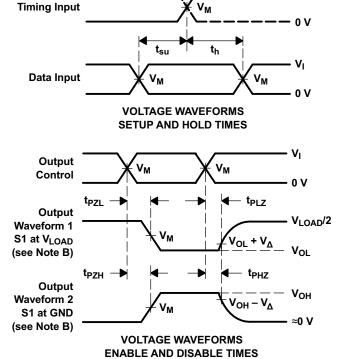
LOAD CIRCUIT

TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

	INF	PUTS			•	1	
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	RL	V
1.8 V ± 0.15 V	V _{cc}	≤2 ns	V _{CC} /2	2 × V _{CC}	30 pF	1 kΩ	0.15 V
2.5 V ± 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	2 × V _{CC}	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
$3.3~V\pm0.3~V$	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V







LOW- AND HIGH-LEVEL ENABLING

VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES INVERTING AND NONINVERTING OUTPUTS

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤10 MHz, Z_O = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{dis} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

8



8 Detailed Description

8.1 Overview

The SN54LVC32A quadruple 2-input positive-OR gate is designed for 2-V to 3.6-V V_{CC} operation, and the SN74LVC32A quadruple 2-input positive-OR gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The SNx4LVC32A devices perform the Boolean function Y = A + B or $Y = \overline{\overline{A} \bullet \overline{B}}$ in positive logic.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as down-translators in a mixed 3.3-V/5-V system environment.

8.2 Functional Block Diagram



8.3 Feature Description

•

- Wide operating voltage range
- Operates from 1.65 V to 3.6 V
- Allows up or down voltage translation
 - Inputs accept voltages to 5.5 V

8.4 Device Functional Modes

Table 1 lists the functional modes of SNx4LVC32A.

Table 1. Function Table	
(Each Gate)	

INP	UTS	OUTPUT
Α	В	Y
Н	Х	Н
Х	Н	Н
L	L	L

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TEXAS INSTRUMENTS

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9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

SN74LVC32A device is a high-drive, CMOS device that can be used for a multitude of buffer-type functions. It can produce 24 mA of drive current at 3 V. Therefore, this device is ideal for driving multiple inputs and for high-speed applications up to 100 MHz. The inputs and outputs are 5.5-V tolerant allowing the device to translate down to V_{CC} .

9.2 Typical Application

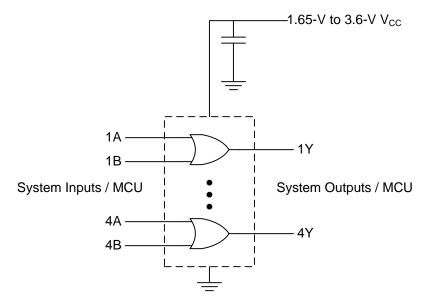


Figure 3. Typical OR Gate Application and Supply Voltage

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs: See ($\Delta t/\Delta V$) in the *Recommended Operating Conditions, SN74LVC32A* table.
 - Specified high and low levels: See (V_{IH} and V_{IL}) in the *Recommended Operating Conditions*, SN74LVC32A table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC} .
- 2. Recommended Output Conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part.
 - Outputs should not be pulled above 5.5 V.



Typical Application (continued)

9.2.3 Application Curve

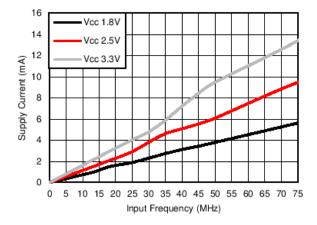


Figure 4. Supply Current vs Input Frequency

10 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions, SN74LVC32A* table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended; if there are multiple V_{CC} pins, then 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and a 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

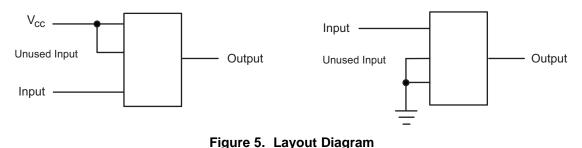
11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. *Layout Example* specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver.

11.2 Layout Example



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12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54LVC32A	Click here	Click here	Click here	Click here	Click here
SN74LVC32A	Click here	Click here	Click here	Click here	Click here

Table 2. Related Links

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9761801Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9761801Q2A SNJ54LVC 32AFK	Samples
5962-9761801QCA	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761801QC A SNJ54LVC32AJ	Samples
5962-9761801QDA	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761801QD A SNJ54LVC32AW	Samples
SN74LVC32AD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32ADBRG4	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ADRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ADT	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ANSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32APW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWE4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWG4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWRG3	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC32APWT	ACTIVE	TSSOP	PW	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32ARGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC32A	Samples
SNJ54LVC32AFK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9761801Q2A SNJ54LVC 32AFK	Samples
SNJ54LVC32AJ	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761801QC A SNJ54LVC32AJ	Samples
SNJ54LVC32AW	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761801QD A SNJ54LVC32AW	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54LVC32A, SN74LVC32A :

- Catalog : SN74LVC32A
- Automotive : SN74LVC32A-Q1, SN74LVC32A-Q1
- Enhanced Product : SN74LVC32A-EP, SN74LVC32A-EP
- Military : SN54LVC32A

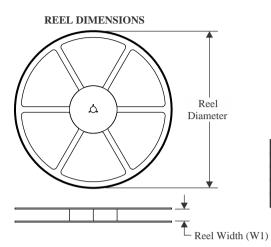
NOTE: Qualified Version Definitions:

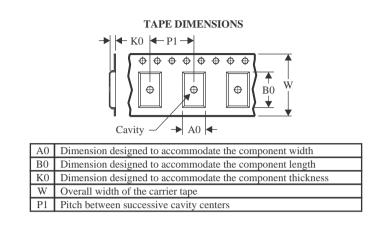
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

TEXAS

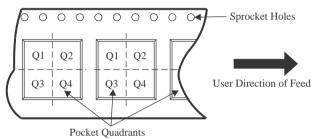
NSTRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

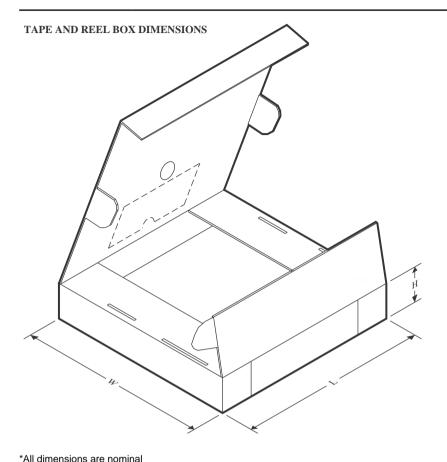


*All dimensions are nominal	<u> </u>				<u> </u>			r				
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC32ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LVC32ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC32ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC32ADT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC32ANSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LVC32APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32APWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32APWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

9-Aug-2022



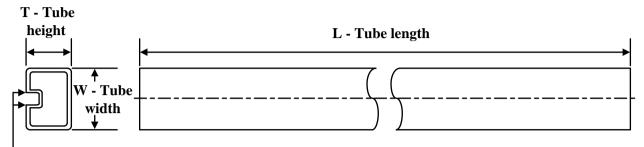
*All dimensions are nominal							r
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC32ADBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74LVC32ADR	SOIC	D	14	2500	340.5	336.1	32.0
SN74LVC32ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LVC32ADT	SOIC	D	14	250	210.0	185.0	35.0
SN74LVC32ANSR	SO	NS	14	2000	356.0	356.0	35.0
SN74LVC32APWR	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LVC32APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC32APWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LVC32APWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC32APWT	TSSOP	PW	14	250	356.0	356.0	35.0
SN74LVC32ARGYR	VQFN	RGY	14	3000	356.0	356.0	35.0

TEXAS INSTRUMENTS

www.ti.com

9-Aug-2022

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
5962-9761801Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
5962-9761801QDA	W	CFP	14	1	506.98	26.16	6220	NA
SN74LVC32AD	D	SOIC	14	50	506.6	8	3940	4.32
SN74LVC32APW	PW	TSSOP	14	90	530	10.2	3600	3.5
SN74LVC32APWE4	PW	TSSOP	14	90	530	10.2	3600	3.5
SN74LVC32APWG4	PW	TSSOP	14	90	530	10.2	3600	3.5
SNJ54LVC32AFK	FK	LCCC	20	1	506.98	12.06	2030	NA
SNJ54LVC32AW	W	CFP	14	1	506.98	26.16	6220	NA

W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only.
 - E. Falls within MIL STD 1835 GDFP1-F14



GENERIC PACKAGE VIEW

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



J0014A



PACKAGE OUTLINE

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



NOTES:

- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



J0014A

EXAMPLE BOARD LAYOUT

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE





D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



MECHANICAL DATA



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- earrow Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.

D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.

- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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